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AMENDMENTS TO THE CLAIMS:

This listing of claims replaces all prior versions and listings of claims in the

application:

LISTING OF THE CLAIMS:

1 to 21. (Cancelled)

22. (Currently Amended) Circuitry for use in a mobile telephone, the circuitry

comprising:

a terminal for use with a high-frequency signal;

at least two signal lines;

a switching unit for connecting the terminal to a signal line; and

a primary protection device for protecting against electrostatic discharges, the

primary protection device being between the terminal and the switching unit, the primary

protection device comprising a first element that diverts all voltages having a pulse

height magnitude greater than a 200V switching voltage along a same path to a reference

potential.

23. (Previously Presented) The circuitry of claim 22, wherein the first element

has an insertion attenuation that is less than 0.3 dB.

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24. (Previously Presented) The circuitry of claim 22, wherein the first element has a capacitance that is less than 1 pF.

- 25. (Previously Presented) The circuitry of claim 22, wherein the first element comprises a gallium arsenide double diode.
- 26. (Previously Presented) The circuitry claim 22, wherein the primary protection device comprises a circuit path that connects the terminal and the switching unit; and

wherein the first element connects the circuit path to the reference potential.

- 27. (Previously Presented) The circuitry of claim 22, further comprising:
 a second element that is in parallel with the first element, the second element for limiting a current load of the first element.
 - 28. (Previously Presented) The circuitry of claim 27, further comprising: a capacitor on a circuit path between the first element and the second element
- 29. (Previously Presented) The circuitry of claim 27, wherein the second element comprises is a discharger.

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30. (Previously Presented) The circuitry of claim 27, wherein the second element comprises a polymer suppressor.

- 31. (Previously Presented) The circuitry of claim 27, wherein the second element comprises an over-voltage component having a capacitance that is less than 1 pF.
- 32. (Previously Presented) The circuitry of claim 27, wherein the second element comprises an inductive element having an inductance that is greater than 18 nH.
- 33. (Previously Presented) The circuitry of claim 22, further comprising: circuit paths that provide control signals to the switching unit, each of the circuit paths comprising a secondary protection device for protecting against electrostatic discharges.
- 34. (Previously Presented) The circuitry of claim 22, further comprising:
 a circuit path for supplying for an operating voltage to the switching unit, the
 circuit path comprising a secondary protection device for protecting against electrostatic
 discharges.

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35. (Previously Presented) The circuitry of claim 22, wherein the switching unit comprises field effect transistors, a contact break distance of each of the field effect transistors connecting the terminal to a signal line; and

wherein the circuitry further comprises:

circuit paths that connect to gates of the field effect transistors, the circuit paths for providing control signals to the gates, each of the circuit paths comprising a secondary protection device for protecting against electrostatic discharges.

- 36. (Previously Presented) The circuitry of claim 33, 34 or 35, wherein the secondary protection device comprises a voltage-limiting element having a switching voltage that is less than 100 V.
- 37. (Previously Presented) The circuitry of claim 36, wherein the voltagelimiting element comprises a varistor.
- 38. (Previously Presented) The circuitry of claim 36, wherein the voltage-limiting element comprises a Zener diode.
- 39. (Previously Presented) The circuitry of claim 35, wherein at least one secondary protection device is connected to the reference potential.

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40. (Previously Presented) The circuitry of claim 22, wherein the switching unit comprises PIN diodes.

- 41. (Previously Presented) The circuitry of claim 22, wherein the switching unit comprises a gallium arsenide switch.
- 42. (Previously Presented) The circuitry of claim 22, wherein the terminal comprises an antenna input of a mobile telephone.
- 43. (Previously Presented) The circuitry of claim 22, wherein the signal lines comprises transmitting and receiving paths of a the mobile telephone.
- 44. (Previously Presented) The circuitry of claim 22, wherein the switching unit and the primary protection device are integrated into a multi-layer ceramic substrate.